



FH102A

RF Transistor 10V, 70mA, $f_T=7\text{GHz}$ NPN Dual MCP6

ON Semiconductor®

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Features

- Composite type with 2 transistors contained in the MCP package currently in use, improving the mounting efficiency greatly
- The FH102A is formed with two chips, being equivalent to the 2SC5226A, placed in one package
- Optimal for differential amplification due to excellent thermal equilibrium and pair capability

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

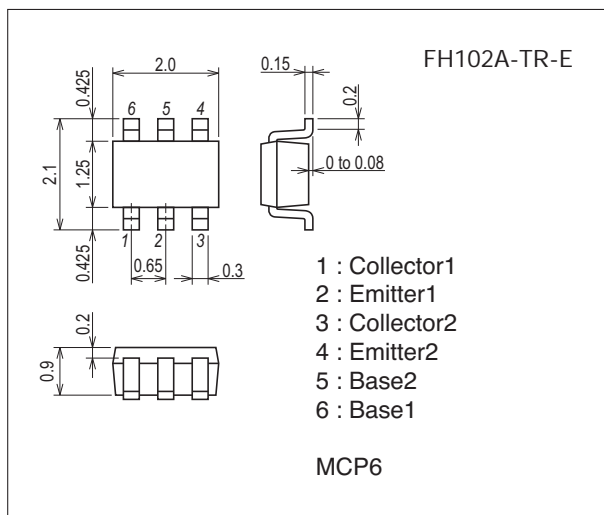
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		20	V
Collector-to-Emitter Voltage	V_{CEO}		10	V
Emitter-to-Base Voltage	V_{EBO}		2	V
Collector Current	I_C		70	mA
Collector Dissipation	P_C	When mounted on ceramic substrate (250mm ² ×0.8mm) 1unit	300	mW
Total Power Dissipation	P_T	When mounted on ceramic substrate (250mm ² ×0.8mm)	500	mW
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

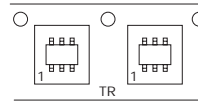
7026A-002



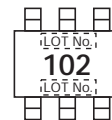
Product & Package Information

- Package : MCP6
- JEITA, JEDEC : SC-88, SC-70-6, SOT-363
- Minimum Packing Quantity : 3,000 pcs./reel

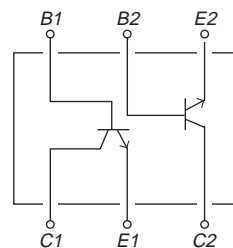
Packing Type : TR



Marking



Electrical Connection



FH102A

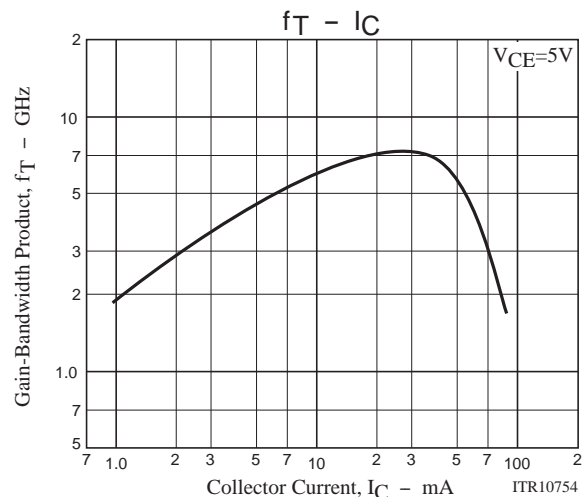
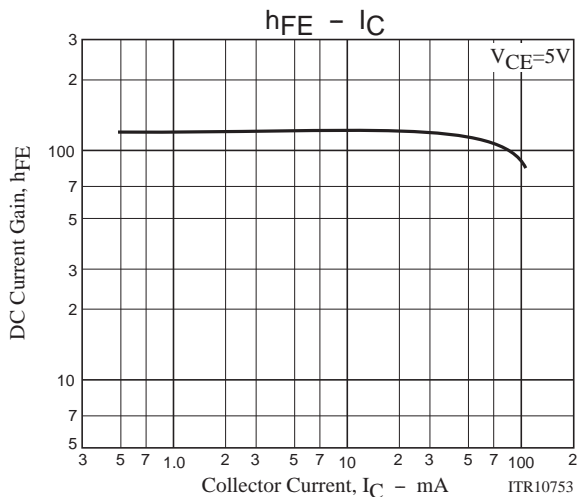
Electrical Characteristics at Ta=25°C

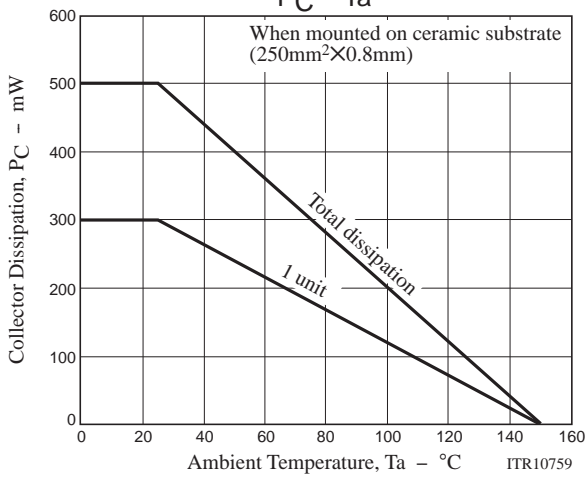
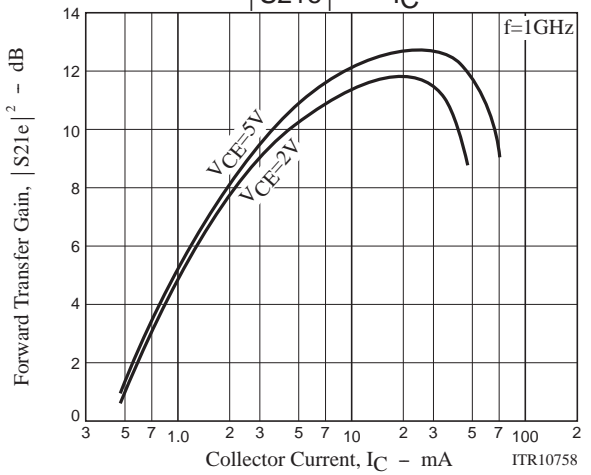
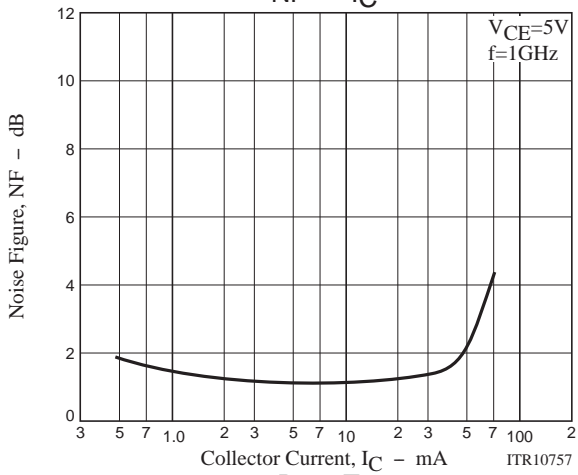
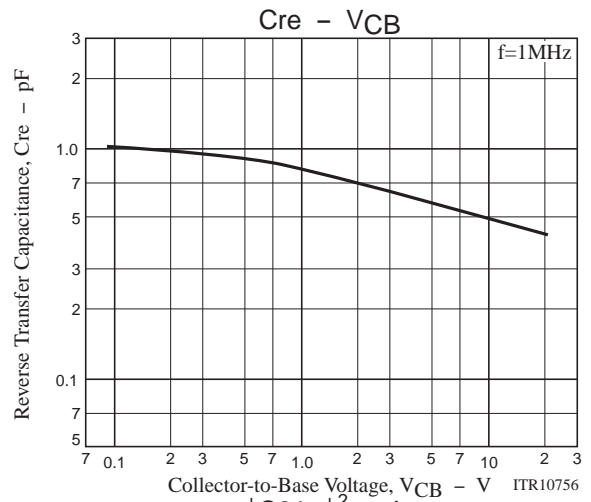
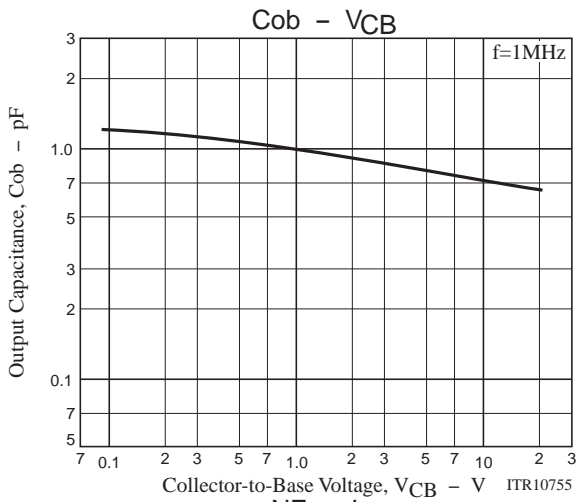
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V _{CB} =10V, I _E =0A			1.0	μA
Emitter Cutoff Current	IEBO	V _{EB} =1V, I _C =0A			10	μA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =20mA	90		200	
DC Current Gain Ratio	h _{FE} (small/large)	V _{CE} =5V, I _C =20mA	0.7	0.95		
Base-to-Emitter Voltage Difference	V _{BE} (large-small)	V _{CE} =5V, I _C =20mA		10		mV
Gain-Bandwidth Product	f _T	V _{CE} =5V, I _C =20mA	5	7		GHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		0.75	1.2	pF
Reverse Transfer Capacitance	C _{re}	V _{CB} =10V, f=1MHz		0.5		pF
Forward Transfer Gain	S _{21e} ² ₁	V _{CE} =5V, I _C =20mA, f=1GHz	9	12		dB
	S _{21e} ² ₂	V _{CE} =2V, I _C =3mA, f=1GHz		8		dB
Noise Figure	NF	V _{CE} =5V, I _C =7mA, f=1GHz		1.0	1.8	dB

Note) The specifications shown above are for each individual transistor except the h_{FE}(small/large) and V_{BE} (large-small) for which pair capability is also shown.

Ordering Information

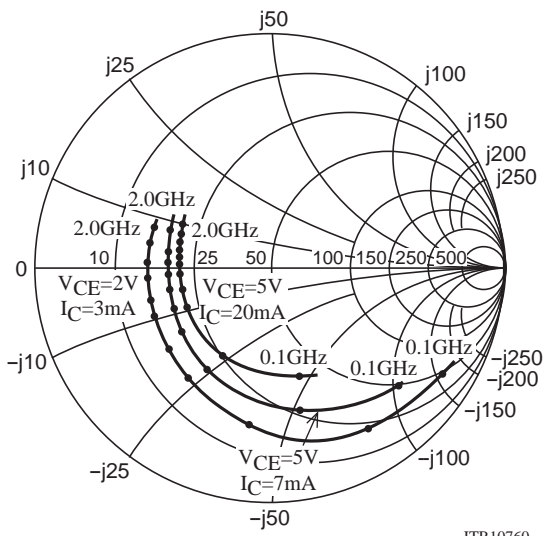
Device	Package	Shipping	memo
FH102A-TR-E	MCP6	3,000pcs./reel	Pb Free





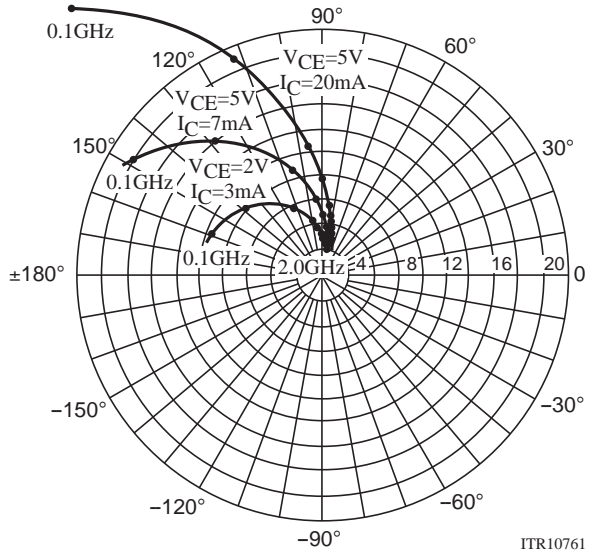
S Parameter

f=100MHz, 200 to 2000MHz(200MHz Step)



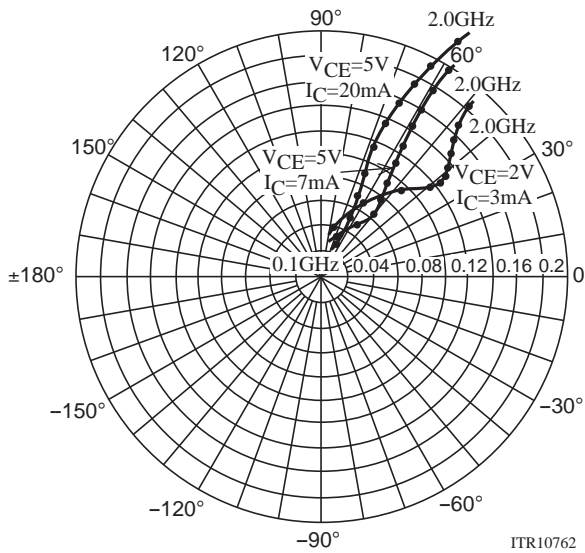
ITR10760

f=100MHz, 200 to 2000MHz(200MHz Step)



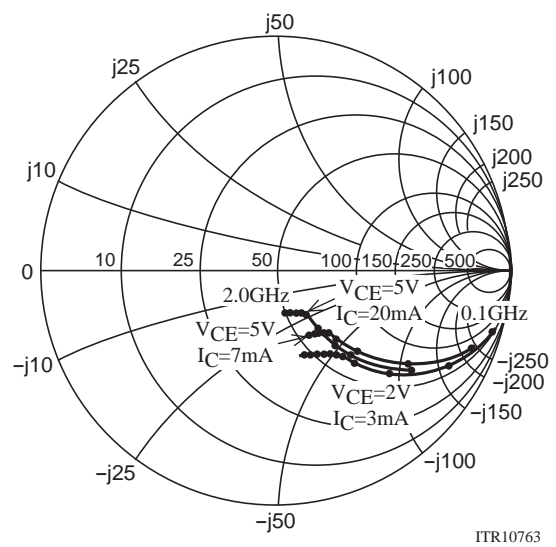
ITR10761

f=100MHz, 200 to 2000MHz(200MHz Step)



ITR10762

f=100MHz, 200 to 2000MHz(200MHz Step)



ITR10763

FH102A

S Parameters (Common emitter)

$V_{CE}=5V, I_C=7mA, Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
100	0.720	-46.0	17.973	148.5	0.030	68.5	0.880	-23.6
200	0.612	-80.9	13.927	127.3	0.047	57.1	0.697	-37.6
400	0.497	-121.3	8.656	105.0	0.066	51.3	0.479	-47.6
600	0.456	-143.5	6.080	92.8	0.079	52.9	0.382	-50.5
800	0.440	-157.6	4.725	84.3	0.094	55.4	0.339	-51.8
1000	0.436	-167.5	3.864	77.0	0.110	56.8	0.323	-53.4
1200	0.434	-176.1	3.258	70.3	0.126	57.9	0.312	-55.8
1400	0.433	176.6	2.847	64.5	0.143	58.4	0.304	-58.3
1600	0.433	170.9	2.329	57.4	0.160	58.9	0.296	-62.0
1800	0.434	165.0	2.252	54.2	0.178	58.6	0.293	-65.0
2000	0.439	159.6	2.057	49.2	0.197	58.1	0.294	-68.1

$V_{CE}=5V, I_C=20mA, Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
100	0.481	-78.8	29.795	132.9	0.022	63.9	0.707	-38.2
200	0.420	-119.2	19.008	112.2	0.033	60.8	0.470	-51.1
400	0.391	-151.6	10.416	95.4	0.052	64.7	0.296	-55.3
600	0.386	-166.4	7.084	86.6	0.071	67.2	0.236	-56.1
800	0.381	-175.9	5.407	80.1	0.092	68.4	0.213	-56.6
1000	0.382	178.2	4.401	74.1	0.114	67.8	0.208	-57.9
1200	0.385	172.1	3.701	68.5	0.134	66.8	0.204	-60.7
1400	0.388	166.7	3.217	63.6	0.156	65.6	0.202	-63.5
1600	0.390	162.1	2.839	58.8	0.176	64.0	0.199	-67.9
1800	0.391	156.7	2.534	54.3	0.197	62.4	0.197	-71.2
2000	0.394	152.1	2.319	50.1	0.219	60.6	0.197	-74.2

$V_{CE}=2V, I_C=3mA, Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
100	0.858	-32.4	9.413	157.2	0.040	72.6	0.945	-16.5
200	0.782	-60.7	8.187	138.5	0.070	59.2	0.833	-29.3
400	0.653	-101.1	5.855	113.8	0.101	44.5	0.637	-43.2
600	0.588	-126.5	4.337	98.4	0.114	39.1	0.515	-50.0
800	0.557	-143.7	3.444	87.7	0.122	38.0	0.454	-53.8
1000	0.543	-156.3	2.871	78.5	0.130	38.6	0.426	-57.1
1200	0.536	-166.8	2.446	70.5	0.137	40.3	0.407	-60.3
1400	0.533	-175.5	2.145	63.5	0.146	42.5	0.393	-63.8
1600	0.527	177.0	1.904	57.1	0.155	45.0	0.382	-68.0
1800	0.525	170.3	1.714	51.7	0.168	47.3	0.379	-72.0
2000	0.528	163.8	1.564	45.9	0.183	49.2	0.378	-75.8

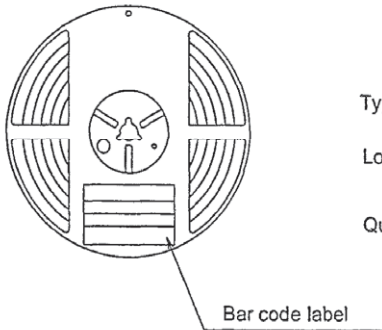
Embossed Taping Specification

FH102A-TR-E

Storage package Outline name	Carrier tape Type number	Maximum Number of devices contained (pcs.)			Packing format	
		Reel	Inner box	Outer box	Inner box BOX (C-1)	Outer box BOX (A-7)
MCP 6	MCP 6	3,000	15,000	90,000	5 reels contained Dimensions:mm(external) 1 8 3 × 7 2 × 1 8 5	6 inner boxes contained Dimensions:mm(external) 4 4 0 × 1 9 5 × 2 1 0

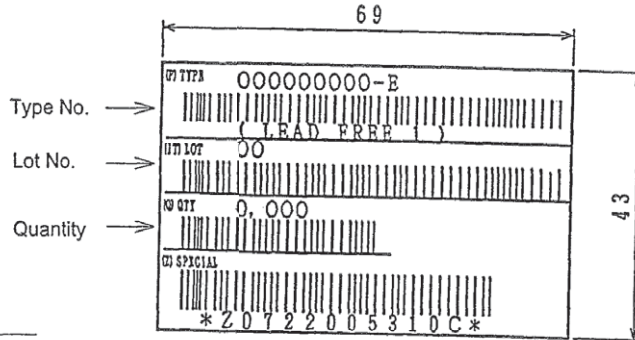
1. Packing format

Packing method



Bar code label

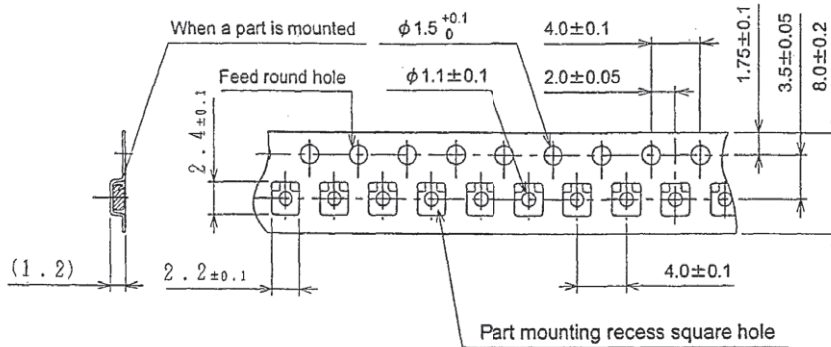
(Unit : mm)



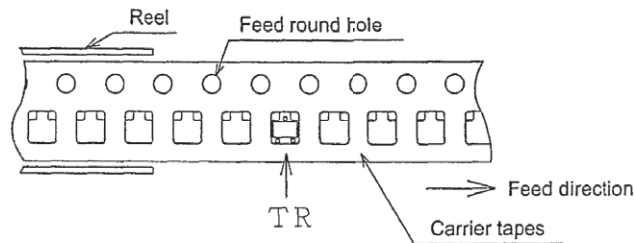
* LEAD FREE 1 :
Lead-free external terminal surface treatment product.

2. Taping structure

2-1. Carrier tape size (Unit : mm)



2-2. Parts placement direction

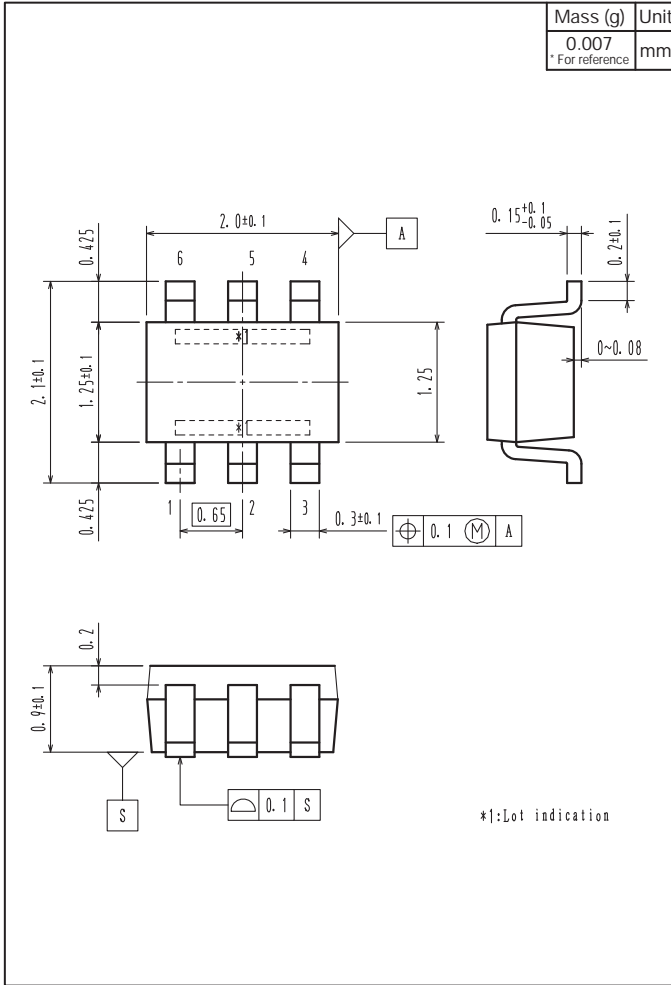


Those with 1 electrode pin on the feed hole side TR

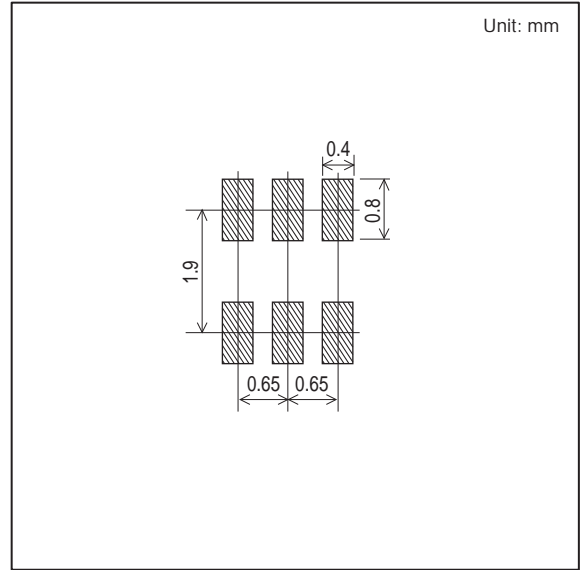
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Outline Drawing

FH102A-TR-E



Land Pattern Example



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